

SPATIAL DISTRIBUTION OF THE ACIS CONTAMINATION

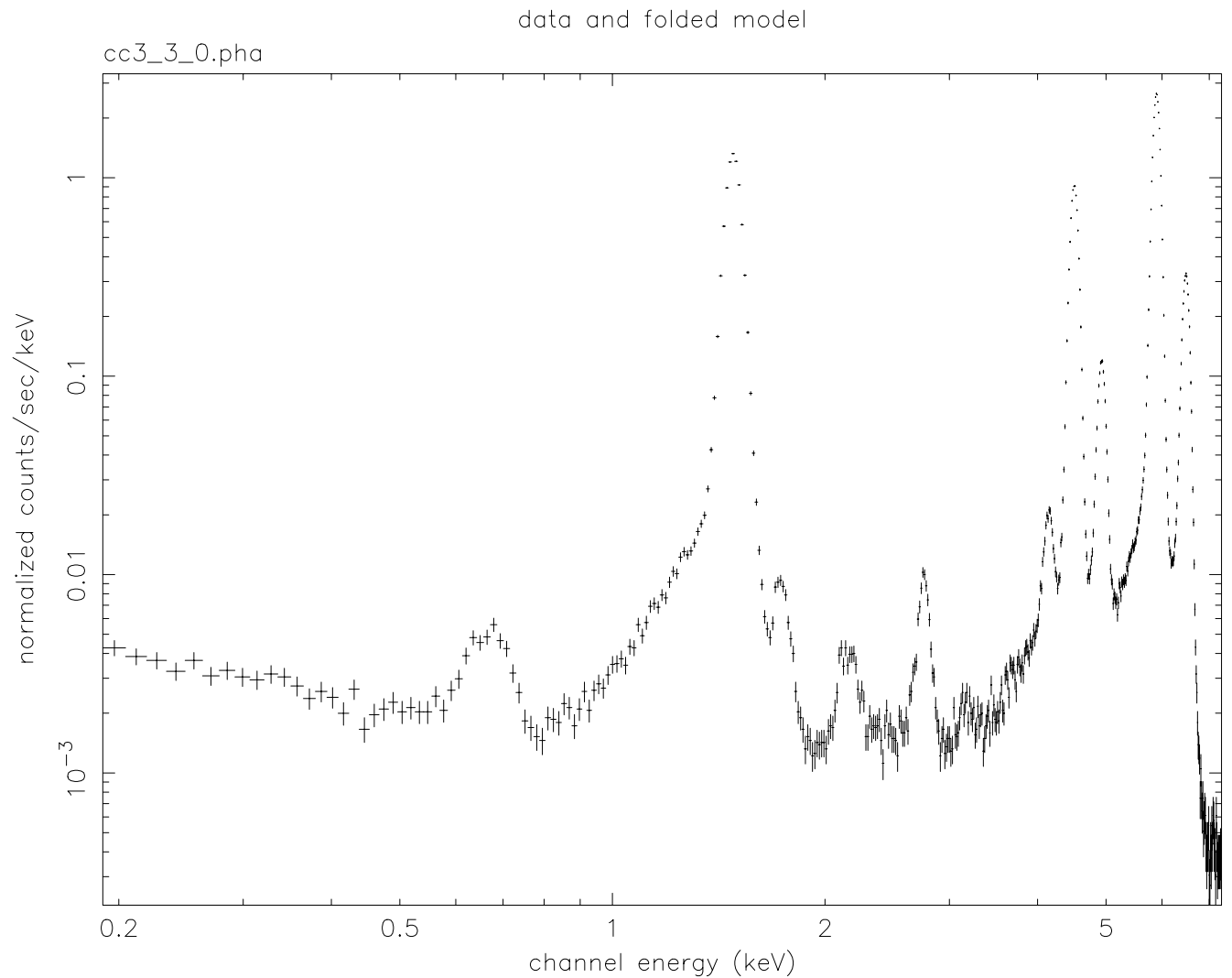
A. Vikhlinin for the ACIS team

June 11, 2003

Data

- External cal. source data accumulated over the 3-month periods since January 2000, (Feb-Apr 2000, May-Jul 2000 and so on). 1-month periods in 1999.
- CTI correction applied to the FI chips.
- `tgain` correction
- use ARF (QE, QEU but no mirror) and RMF appropriate for each region.

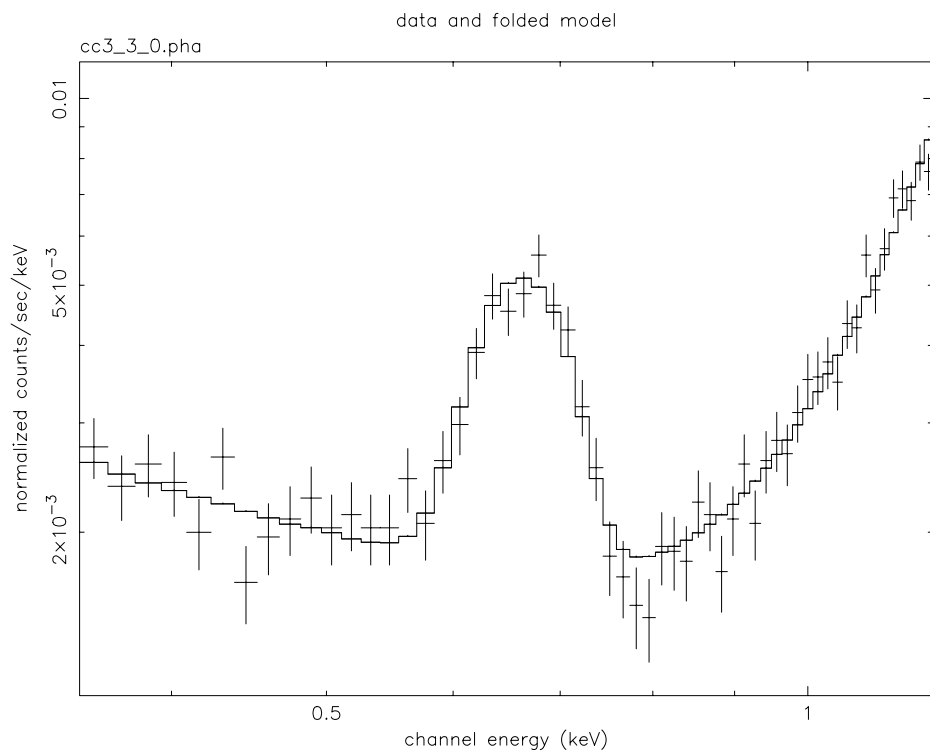
Spectral model



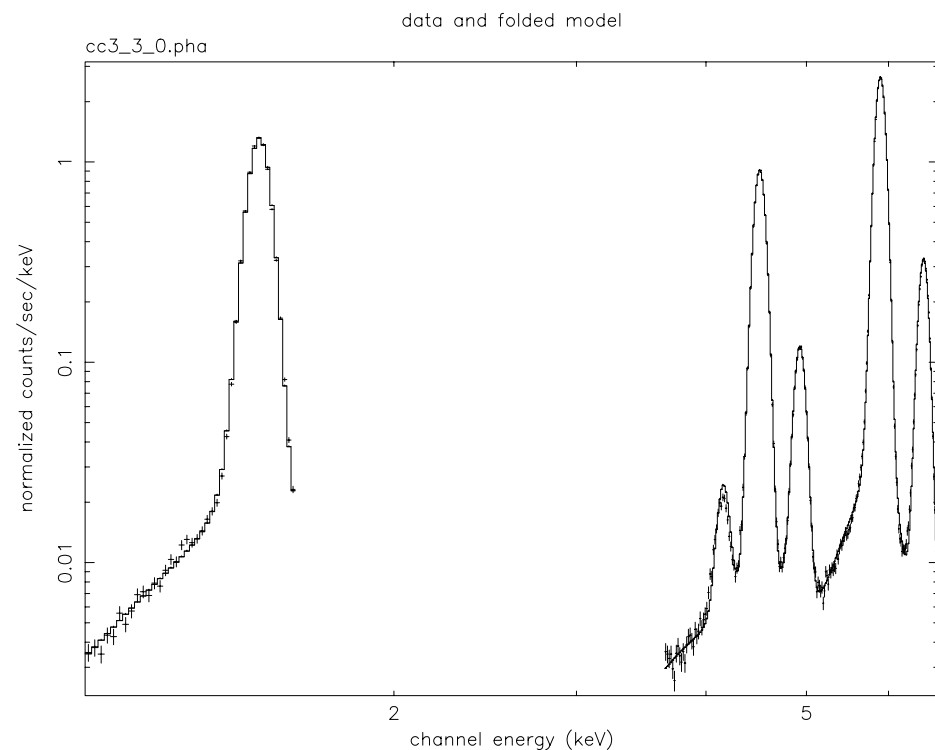
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1. Power law representing the low energy tails of the bright Mn and Ti and also
2. Exponential, $\exp(-(1.487 - E)/\delta E)$, representing the tail of the Al-K line.
3. Two gaussians of equal flux with central energies allowed to vary between 0.62 and 0.72 keV and internal widths constrained to be $\sigma < 20$ eV.
4. Gaussian+exponential tail for high-energy lines

Fit examples



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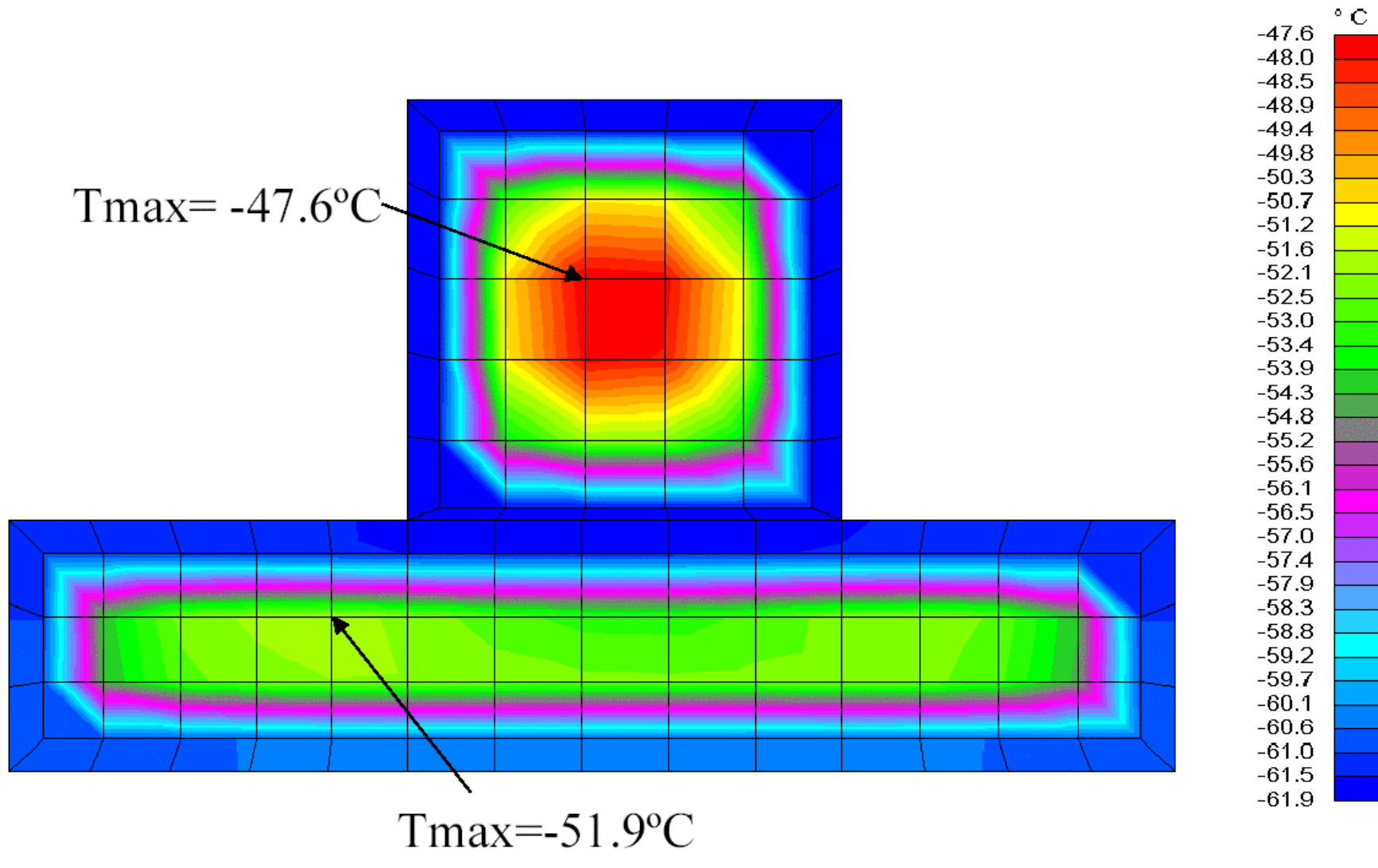


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- Multiply L/K flux ratio by the ratio of nominal quantum efficiencies at 5.89 and 0.67 keV (takes out CTI-induced QE non-uniformities)
- $\tau = \ln(L/K)_{\text{pre-launch}} - \ln(L/K)$

NB. OBF Temperature model

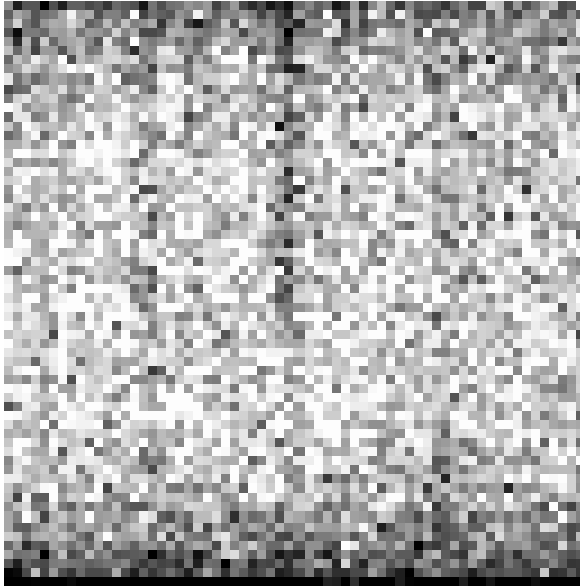
ACIS Housing -60°C, FP -120°C



Spatial structure

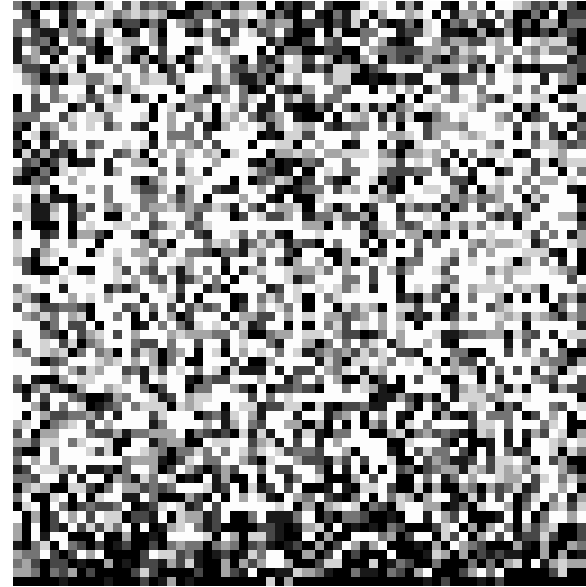
ACIS-S

ACIS S3, Feb2001-Jan2003, 0.55-0.8 keV



cx,cy=0

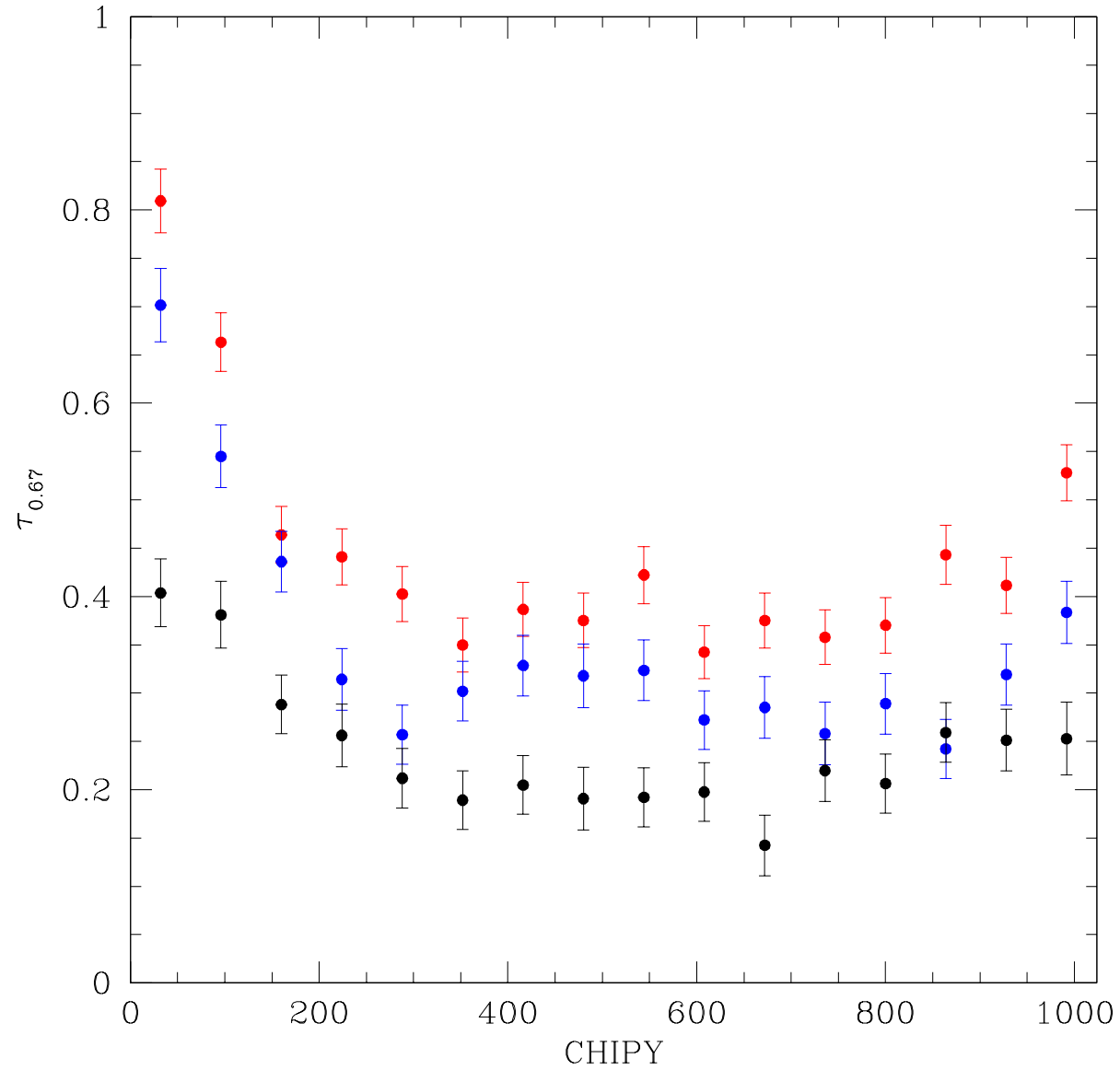
ACIS S2, Feb2001-Jan2003, 0.55-0.8 keV



cx,cy=0

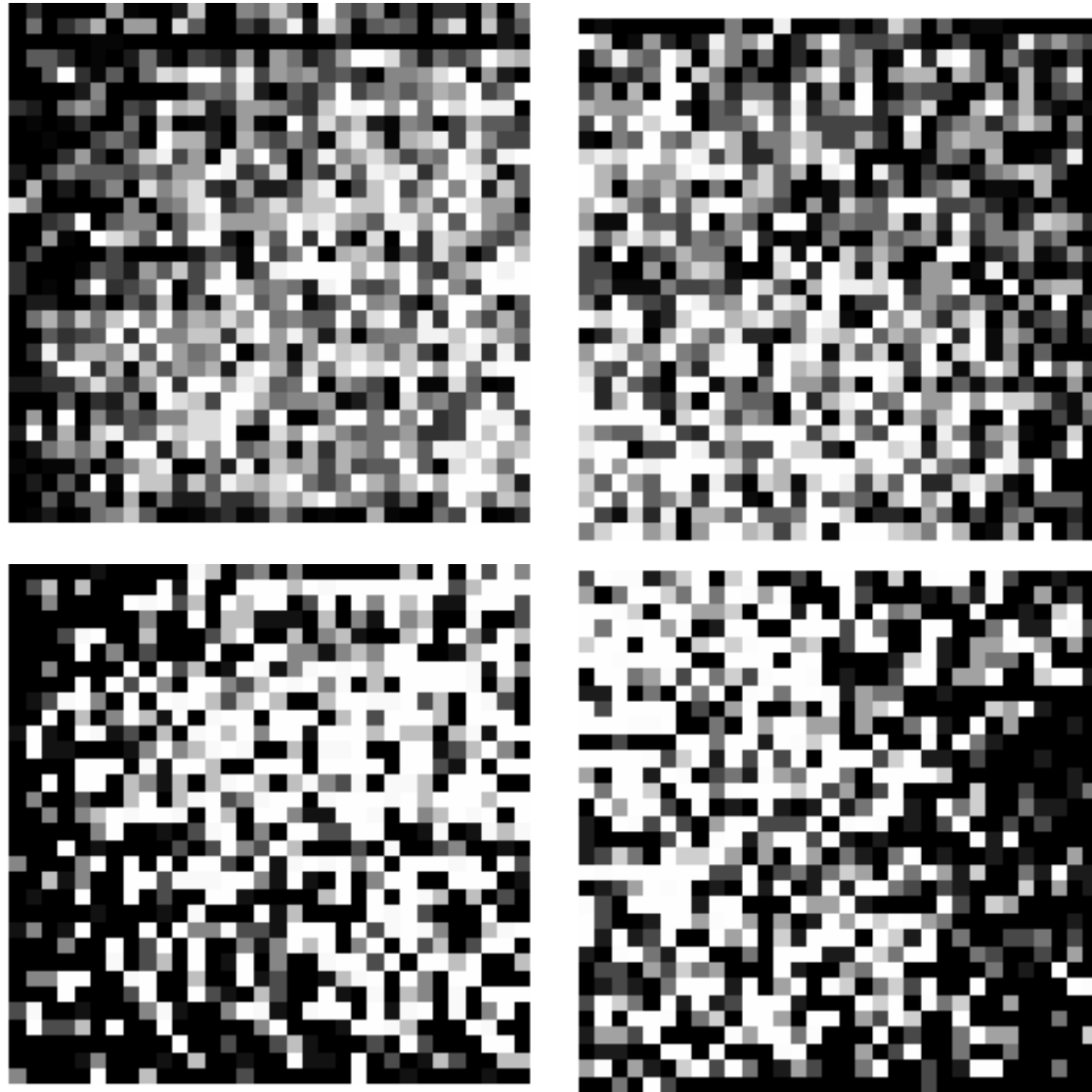
External cal source image in S3 and S2 in the 0.55–0.8 keV band (the Mn/Fe L complex) over Feb 2001 – Jan 2003.

$\tau(\text{CHIPY})$ in ACIS-S



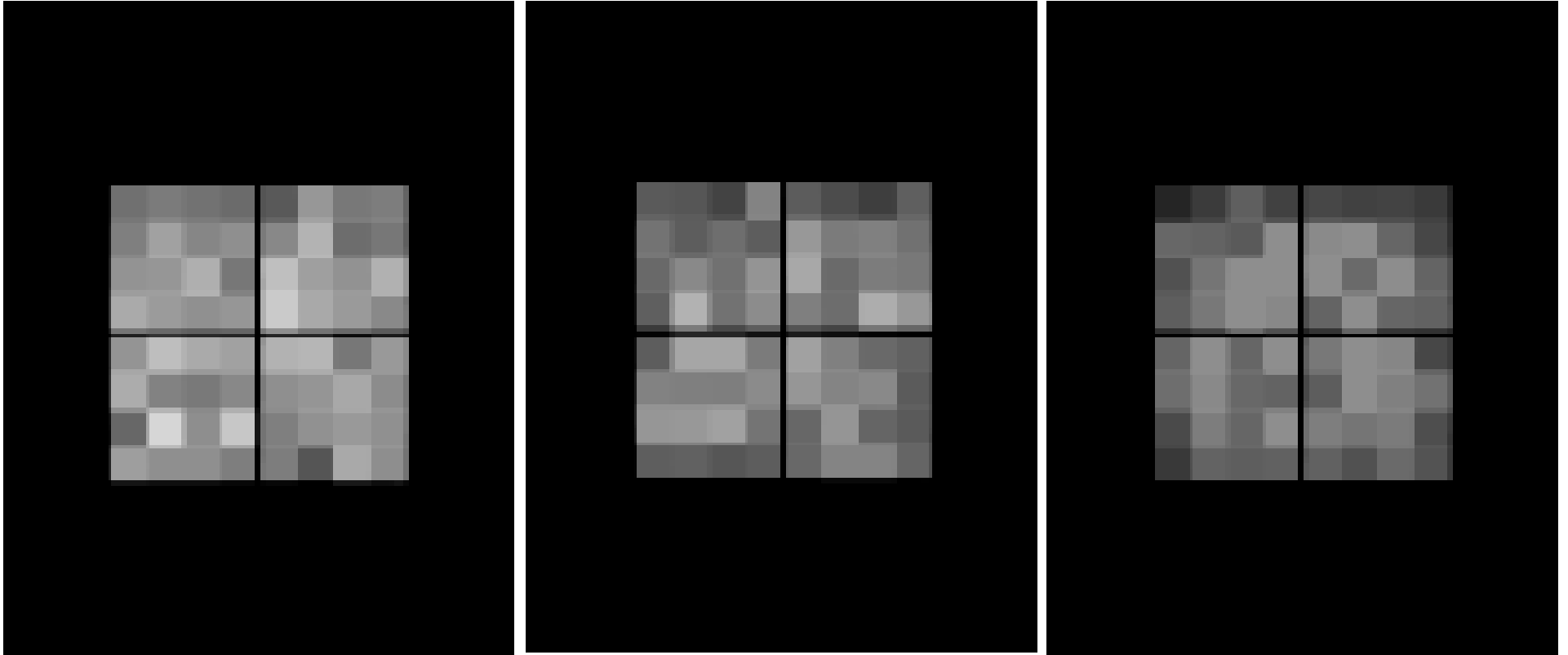
Black: Feb-Jul 2000, Blue: Aug2000-Jul2001, Red: Aug2001-Jul2002.

ACIS-I



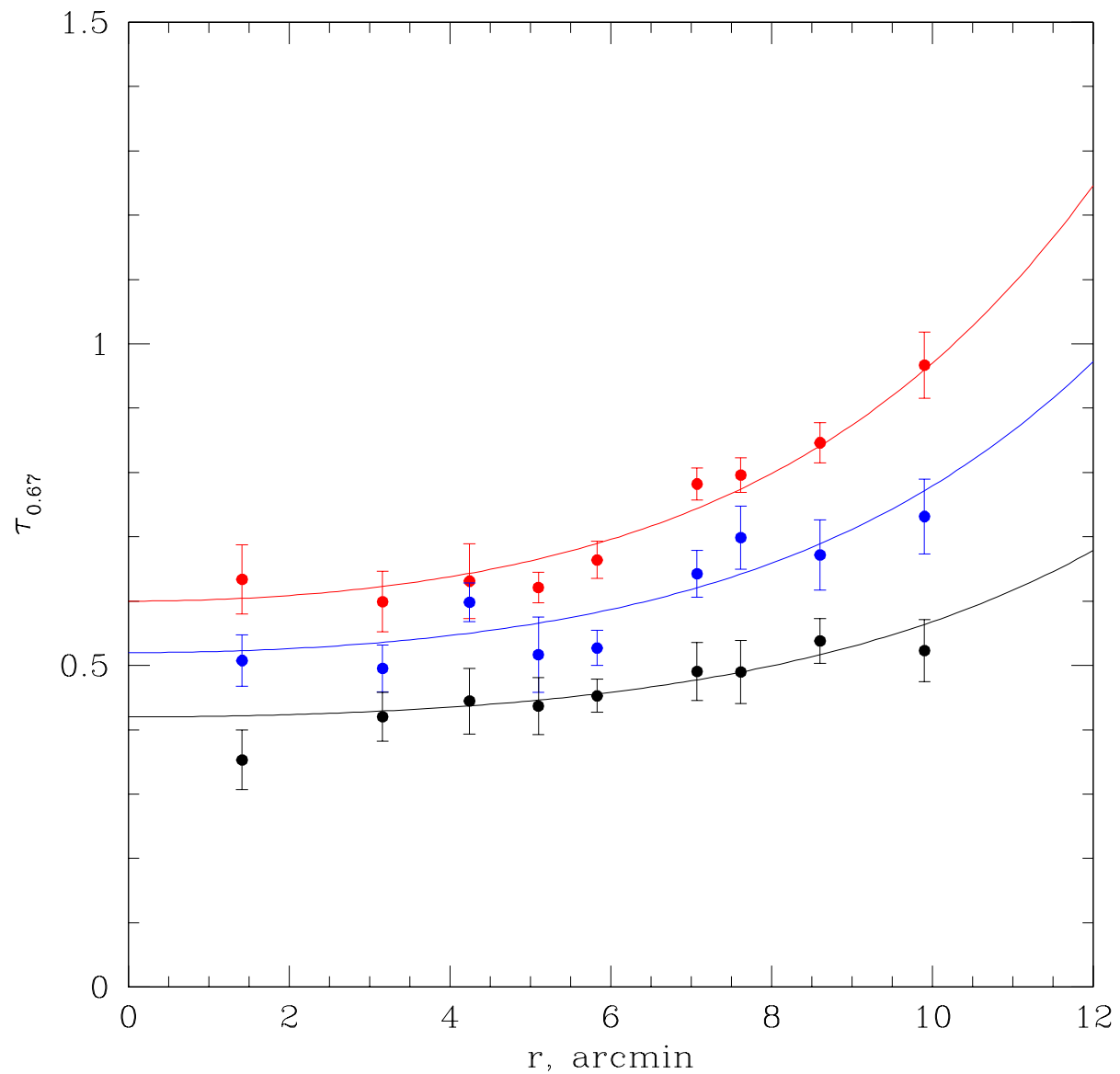
External cal source image in ACIS-I in the 0.55–0.8 keV band over Feb 2001 – Jan 2003. I0 is top-left, I1 is top-right, I2 is bottom-left, and I3 is bottom-right.

$\tau(\mathbf{x}, \mathbf{y})$ in ACIS-I



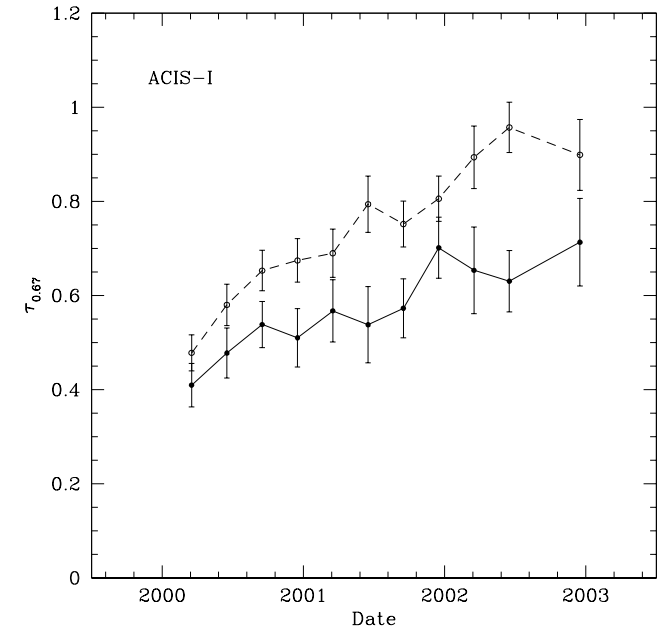
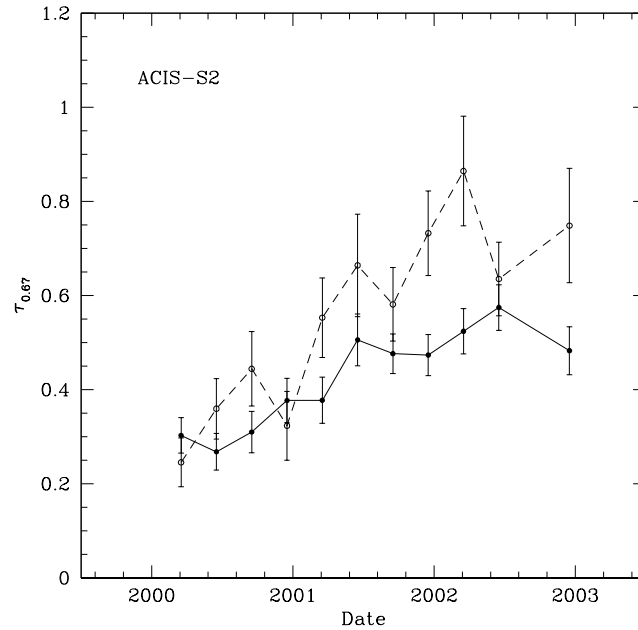
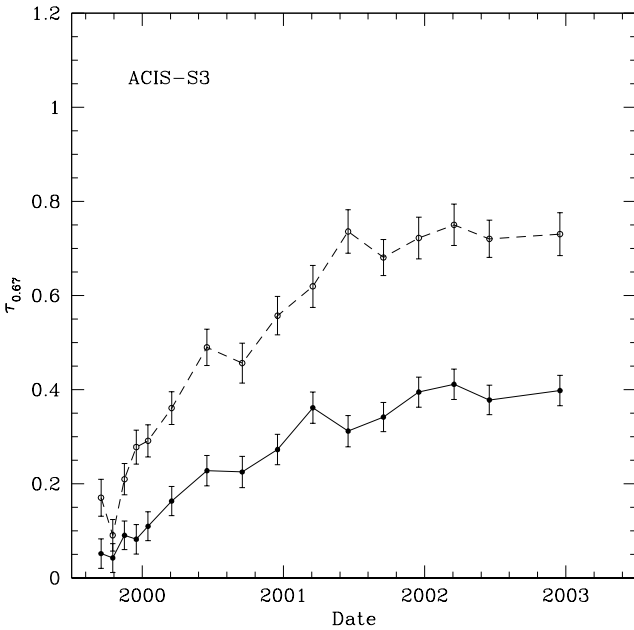
Feb-Jul 2000 (left), Aug2000-Jul2001 (middle), and Aug2001-Jul2002 (right).

$\tau(r)$ in ACIS-I



Feb-Jul 2000 (black), Aug2000-Jul2001 (blue), and Aug2001-Jul2002 (red). The analytic models are in the form $\tau = A + B(r/10.8')^5$.

Time dependence



Filled circles: center, Open circles: border. For ACIS-S, the center is $256 < CHIPY < 768$ and border is $CHIPY < 128$. For ACIS-I the border region is the 256 pixels wide frame along the border of the array, and center is an $8' \times 8'$ square centered on the aim point.

Further work

- Differences in τ between ACIS imaging and HETG/LETG measurements (contamination in S1, different growth rate for C and O?)
- Differences between S2 and S3.
- Software:
 - make $\tau_{0.67}(x, y)$ maps for each epoch
 - use $\tau(E)$ from `contamarf`
 - compute corrections and verify with available data (E0102-37, Cas-A, some clusters).

Summary

- Significant spatial variations of the Mn,Fe-L and Mn-Ka flux ratio suggest that the contamination buildup is non-uniform.
- There is less contaminant in the centers of both CCD arrays where the filter temperature is higher.
- The optical depth grows faster near the readout of ACIS-S and along the border of ACIS-I.
- L/K ratio in the centers of ACIS-I and ACIS-S2 indicates that there is more contaminant on the I-array, $\Delta\tau(0.67\text{keV}) = 0.15$.